

East 8 USPB USPT, WPID, JPO

Ref #	Hits	Search Query	DBs	Default Operator	Plurals	Time Stamp
L1	3300	shih-c\$ or lin-g\$ or lu-I\$ or chih-j\$ or lin-l\$ or lu-m\$	US-PGPUB; USPAT	OR	ON	2005/10/27 20:53
L2	159058	lcd or "liquid crystal display"	US-PGPUB; USPAT	OR	ON	2005/10/27 20:54
L3	221	1 and 2	US-PGPUB; USPAT	OR	ON	2005/10/27 20:45
L4	3644	ltps or "thin film transistor liquid crystal display"	US-PGPUB; USPAT	OR	ON	2005/10/27 20:54
L5	26	3 and 4	US-PGPUB; USPAT	OR	ON	2005/10/27 20:46
L6	39718	tft or "thin film transistor"	US-PGPUB; USPAT	OR	ON	2005/10/27 21:23
L7	26	5 and 6	US-PGPUB; USPAT	OR	ON	2005/10/27 20:47
L8	97099	"p-type" or "p type"	US-PGPUB; USPAT	OR	ON	2005/10/27 20:54
L9	7	7 and 8	US-PGPUB; USPAT	OR	ON	2005/10/27 20:51
L10	172	toppoly.as.	US-PGPUB; USPAT	OR	ON	2005/10/27 20:54
L11	20	2 and 4 and 6 and 8 and 10	US-PGPUB; USPAT	OR	ON	2005/10/27 20:51
L12	17	11 not 9	US-PGPUB; USPAT	OR	ON	2005/10/27 20:52
L13	2929	shih-c\$ or lin-g\$ or lu-I\$ or chih-j\$ or lin-l\$ or lu-m\$	JPO; DERWENT	OR	ON	2005/10/27 20:53
L14	409	toppoly	JPO; DERWENT	OR	ON	2005/10/27 20:54
L15	211368	lcd or "liquid crystal display"	JPO; DERWENT	OR	ON	2005/10/27 20:54
L16	2102	ltps or "thin film transistor liquid crystal display"	JPO; DERWENT	OR	ON	2005/10/27 20:54
L17	40430	tft or "thin film transistor"	JPO; DERWENT	OR	ON	2005/10/27 20:54
L18	77851	"p-type" or "p type"	JPO; DERWENT	OR	ON	2005/10/27 20:54
L19	2	(13 or 14) and 15 and 16 and 17 and 18	JPO; DERWENT	OR	ON	2005/10/27 21:19
L20	1974	15 and 16	JPO; DERWENT	OR	ON	2005/10/27 21:12
L21	23085	storage with electrode	JPO; DERWENT	OR	ON	2005/10/27 21:12
L22	49	20 and 21	JPO; DERWENT	OR	ON	2005/10/27 21:12

L23	455933	poly or polyc\$ or polysi\$	JPO; DERWENT	OR	ON	2005/10/27 21:12
L24	4	22 and 23	JPO; DERWENT	OR	ON	2005/10/27 21:13
L25	4	gate and 24	JPO; DERWENT	OR	ON	2005/10/27 21:18
L26	7	(15 or 16) and 18 and 21 and gate	JPO; DERWENT	OR	ON	2005/10/27 21:18
L27	6	26 not 25	JPO; DERWENT	OR	ON	2005/10/27 21:18
L28	5	27 not 19	JPO; DERWENT	OR	ON	2005/10/27 21:19
L29	3070	(4 or 6) with 8	US-PGPUB; USPAT	OR	ON	2005/10/27 21:24
L30	290	29 same (2 or 4)	US-PGPUB; USPAT	OR	ON	2005/10/27 21:24
L31	13483	storage same gate same electrode	US-PGPUB; USPAT	OR	ON	2005/10/27 21:24
L32	19	30 same 31	US-PGPUB; USPAT	OR	ON	2005/10/27 21:24
L33	2541188	etch\$ or patern\$ or remov\$	US-PGPUB; USPAT	OR	ON	2005/10/27 21:24
L34	7	32 same 33	US-PGPUB; USPAT	OR	ON	2005/10/27 21:24
L35	502250	resist or photoresist or mask or photomask	US-PGPUB; USPAT	OR	ON	2005/10/27 21:25
L36	7	34 same 35	US-PGPUB; USPAT	OR	ON	2005/10/27 21:25